Table 2: Absolute Ratings (limiting values)

Symbol	Param	Value	Unit		
	RMS on-state current full cycle sine	TO-220FPAB	Tcase = 90°C	8	
I _{T(RMS)}	wave 50 to 60 Hz	TO-220AB / D ² PAK	Tcase = 100°C	8	Α
Izora	Non repetitive surge peak on-state co	urrent	t _p = 20ms	80	Α
ITSM	T _j initial = 25°C, full cycle sine wave		t _p = 16.7ms	85	Α
l ² t	Thermal constraint for fuse selection	tp = 10ms	35	A ² s	
dI/dt	Non repetitive on-state current critical $I_G = 10$ mA ($t_r < 100$ ns)	Rate period > 1mn	100	A/µs	
V _{PP}	Non repetitive line peak pulse voltage note			2	kV
T _{stg}	Storage temperature range	- 40 to + 150	°C		
T _j	Operating junction temperature range			- 40 to + 125	°C
T _I	Maximum lead soldering temperature		260	°C	

Note 1: according to test described by IEC61000-4-5 standard & figure A.

Table 3: Gate Characteristics (maximum values)

Symbol	Parameter	Value	Unit
P _{G (AV)}	Average gate power dissipation	0.1	W
P _{GM}	Peak gate power dissipation ($t_p = 20\mu s$)	10	W
I _{GM}	Peak gate current (t _p = 20µs)	1	Α

Table 4: Thermal Resistance

Symbol	Parameter		Value	Unit
R _{th(j-a)}	Junction to ambient	TO-220FPAB TO-220AB	60	°C/W
R _{th(j-a)}	Junction to ambien (soldered on 1 cm ² copper pad)	D ² PAK	45	°C/W
R _{th(j-c)}	Junction to case for full cycle sine wave conduction	TO-220FPAB	3.5	°C/W
R _{th(j-c)}	Junction to case for full cycle sine wave conduction	TO-220AB D ² PAK	2.5	°C/W

Table 5: Parameter Description

Parameter Symbol	Parameter description	
I _{GT}	Gate triggering current	
V_{GT}	Gate triggering voltage	
V_{GD}	Non triggering voltage	
I _H	Holding current	
lμ	Latching current	
V_{TM}	On state voltage	
V_{T0}	On state characteristic threshold voltage	
R _d	On state characteristic dynamic resistance	
I _{DRM} / I _{RRM}	Forward or reverse leakage current	
dV/dt	Static pin OUT voltage rise	
(dl/dt)c	Turn off current rate of decay	
V_{CL}	Avalanche voltage at turn off	

Table 6: Electrical Characteristics per Switch

For either positive or negative polary of pin OUT voltage respect to pin COM voltage

Symbol	Test conditions			Values	Unit
V _{DRM} / V _{RRM}	Repetitive peak off-state voltage		MAX.	800	V
I _{GT}	$V_{OUT} = 12V (DC) R_L = 33\Omega$	$T_j = 25^{\circ}C$	MAX.	30	mA
V _{GT}	$V_{OUT} = 12V (DC) R_L = 33\Omega$	$T_j = 25^{\circ}C$	MAX.	1.5	V
V_{GD}	$V_{OUT} = V_{DRM}$ $R_L = 3.3k\Omega$	$T_j = 125^{\circ}C$	MIN.	0.2	V
I _H	I _{OUT} = 100mA Gate open	T _j = 25°C	MAX.	40	mA
ΙL	I _G = 20mA	$T_j = 25^{\circ}C$	MAX.	70	mA
V _{TM}	$I_{OUT} = 11A$ $t_p = 380 \mu s$	T _j = 25°C	MAX.	1.5	V
V _{T0}		$T_j = 125^{\circ}C$	MAX.	0.95	V
R _d		$T_j = 125^{\circ}C$	MAX.	50	mΩ
I _{DRM} /	$V_{OUT} = V_{DRM}$	T _j = 25°C	MAX.	10	μA
I _{RRM}	$V_{OUT} = V_{RRM}$	$T_j = 125^{\circ}C$	MAX.	1	mA
dV/dt	V _{OUT} = 550V gate open	$T_j = 125^{\circ}C$	MIN.	750	V/µs
(dl/dt)c	Without snubber	$T_j = 125^{\circ}C$	MIN.	4.5	A/ms
V _{CL}	$I_{CL} = 1 \text{mA}$ $t_p = 1 \text{ms}$	T _j = 25°C	TYP.	1200	V

1. AC LINE SWITCH BASIC APPLICATION

The ACST8-8C device is especially designed to drive medium power induction motors in washing machines, refrigerators, dish washers, and tumble dryers.

Pin COM : Common drive reference, to be connected to the power line neutral

Pin G : Switch Gate input to be connected to the controller

Pin OUT : Switch Output to be connected to the load

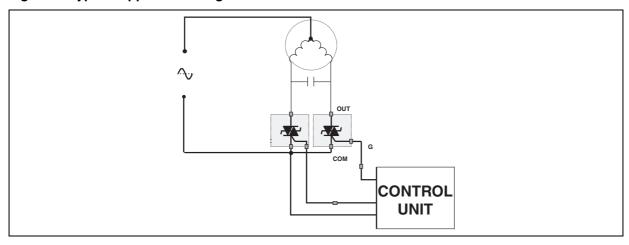
When driven from a low voltage controller, the ACST switch is triggered with a negative gate current flowing out of the gate pin G. It can be driven by the controller through a resistor as shown on the typical application diagram. In appliance systems, the ACST8-8C switch intends to drive medium power load in ON / OFF full cycle or phase angle control mode.

Thanks to its thermal and turn-off commutation characteristics, the ACST8-8C switch is able to drive an inductive load up to 8A without a turn-off aid snubber circuit.

In washing machine or drier appliances, the tumble rotates in both directions. When using bidirectional phase shift induction motor, two switches are connected on each side of the phase shift capacitor: in steady-state operation, one switch only conducts energising the coils and defining the tumble direction.

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Figure 2: Typical Application Diagram



2. ROBUSTNESS AGAINST FAST CAPACITOR DISCHARGE

When parasitic transients or controller mis-operation occur, the blocked switch may turn on by spurious switch firing. Since the phase shift capacitor is charged, its energy is instantaneously dissipated through the two ACSTs which can be destroyed. To prevent such a failure, a resistive inductive circuit R-L is added in series with the phase shift capacitor.

The dl/dt depends on the maximal voltage V_{max} of the phase shift capacitor (700V on 240V mains applications), and on the inductance L:

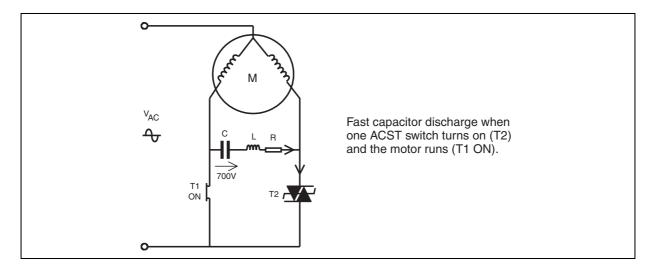
$$\frac{dI}{dt} = \frac{v_{\text{max}}}{L}$$

The total switch turn on di/dt is the sum of the di/dt created by any RC noise suppressor discharge and the dl/dt created by the motor capacitor discharge.

Since the maximal dI/dt capability at turn-on of the ACST8 is $100A/\mu s$, the motor capacitor di/dt is assumed to be less than $50A/\mu s$; therefore, the inductance should be $14\mu H$.

The resistor R limits the surge current through the ACST8 during the capacitor discharge according to the specified curve $I_{TSM} = f$ (tp) as shown in figure 11 (to be issued), and 1.2 Ω is low enough to limit the resistor dissipation (usually less than 1 W).

Finally both the $14\mu H$ inductance and the 1.2Ω resistance provide a safety margin of two on the surge current I_{TSM} described in figure 11.



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3. AC LINE TRANSIENT VOLTAGE RUGGEDNESS

The ACST8-8C switch is able to safely withstand the AC line transient voltages either by clamping the low energy spikes or by breaking over under high energy shocks.

The test circuit in figure 3 is representative of the ACST application and is used to test the ACST switch according to the IEC61000-4-5 standard conditions. Thanks to the load impedance, the ACST switch withstands voltage spikes up to 2 kV above the peak line voltage by breaking over safely. Such non repetitive testing can be done 10 times on each AC line voltage polarity.

Figure 3: Overvoltage ruggedness test circuit for resistive and inductive loads according to IEC61000-4-5 standard R = 47Ω , L = 10μ H & V_{PP} = 2kV

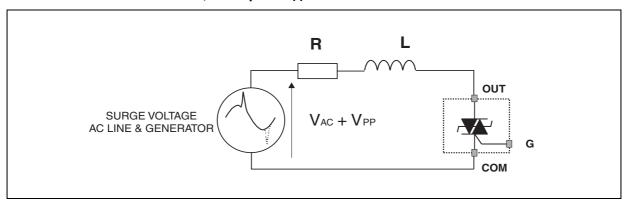


Figure 4: Maximum power dissipation versus RMS on-state current

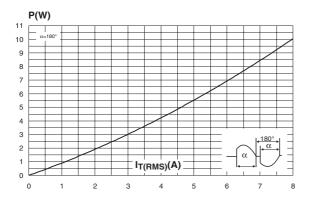


Figure 5: RMS on-state current versus case temperature

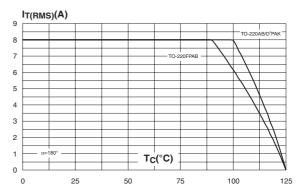


Figure 6: RMS on-state current versus ambient temperature

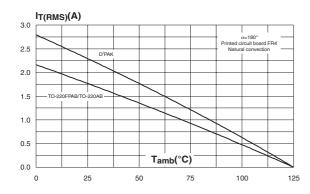
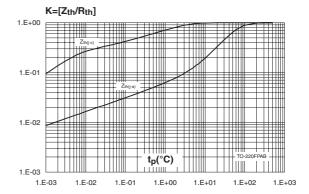


Figure 7: Relative variation of thermal impedance versus pulse duration (TO-220FPAB)



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Figure 8: Relative variation of thermal impedance versus pulse duration (TO-220AB / D²PAK)

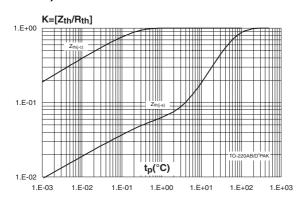


Figure 10: Surge peak on-state current versus number of cycles

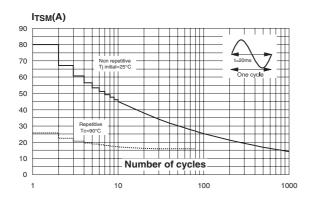


Figure 12: Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values)

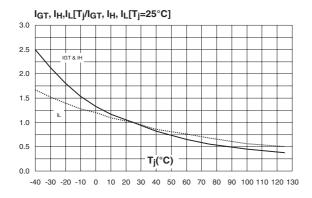


Figure 9: On-state characteristics (maximum values)

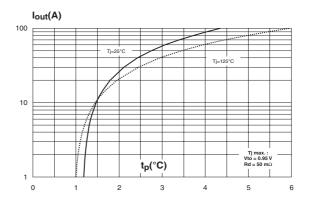


Figure 11: Non repetitive surge peak on-state current for a sinusoidal pulse with width tp < 10ms, and corresponding value of I^2t

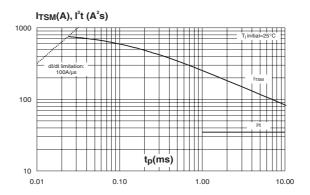


Figure 13: Relative variation of critical rate of decrease of main current versus reapplied dV/ dt (typical values)

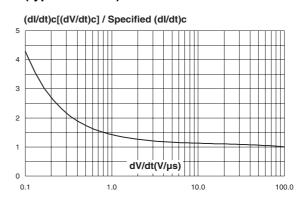


Figure 14: Relative variation of critical rate of decrease of main current versus junction temperature

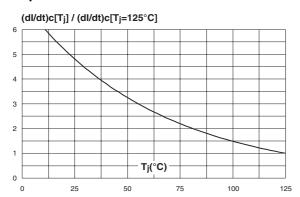


Figure 15: Relative variation of static dV/dt versus junction temperature

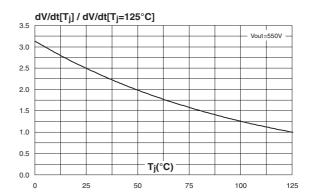


Figure 16: Surge peak on-state current versus number of cycles

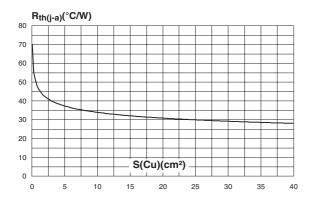
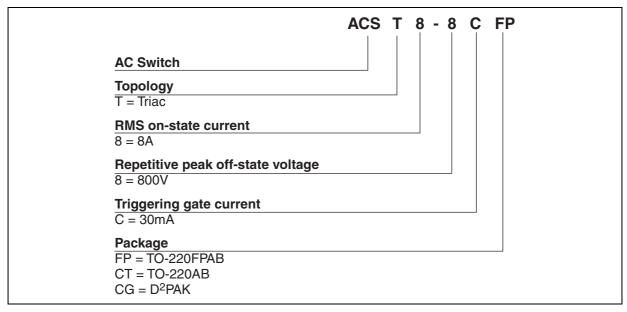
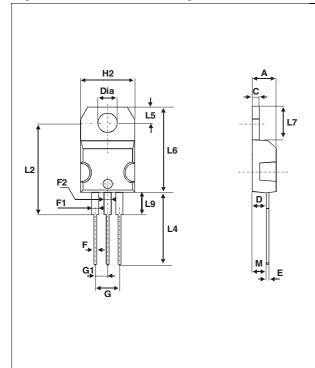


Figure 17: Ordering Information Scheme



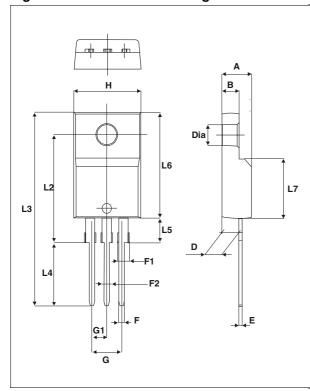
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Figure 18: TO-220AB Package Mechanical Data



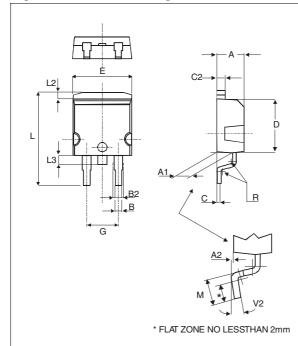
		DIMEN	ISIONS	
REF.	Millin	neters	Inches	
	Min.	Max.	Min.	Max.
Α	4.40	4.60	0.173	0.181
В	1.23	1.32	0.048	0.051
D	2.40	2.72	0.094	0.107
Е	0.49	0.70	0.019	0.027
F	0.61	0.88	0.024	0.034
F1	1.14	1.70	0.044	0.066
F2	1.14	1.70	0.044	0.066
G	4.95	5.15	0.194	0.202
G1	2.40	2.70	0.094	0.106
H2	10	10.40	0.393	0.409
L2	16.4	typ.	0.645 typ.	
L4	13	14	0.511	0.551
L5	2.65	2.95	0.104	0.116
L6	15.25	15.75	0.600	0.620
L7	6.20	6.60	0.244	0.259
L9	3.50	3.93	0.137	0.154
М	2.6 typ.		0.102	2 typ.
Diam.	3.75	3.85	0.147	0.151

Figure 19: TO-220FPAB Package Mechanical Data



		DIMEN	ISIONS	SIONS			
REF.	Millin	neters	Inches				
·	Min.	Max.	Min.	Max.			
Α	4.4	4.6	0.173	0.181			
В	2.5	2.7	0.098	0.106			
D	2.5	2.75	0.098	0.108			
Е	0.45	0.70	0.018	0.027			
F	0.75	1	0.030	0.039			
F1	1.15	1.70	0.045	0.067			
F2	1.15	1.70	0.045	0.067			
G	4.95	5.20	0.195	0.205			
G1	2.4	2.7	0.094	0.106			
Н	10	10.4	0.393	0.409			
L2	16	Гур.	0.63	Тур.			
L3	28.6	30.6	1.126	1.205			
L4	9.8	10.6	0.386	0.417			
L5	2.9	3.6	0.114	0.142			
L6	15.9	16.4	0.626	0.646			
L7	9.00	9.30	0.354	0.366			
Dia.	3.00	3.20	0.118	0.126			

Figure 20: D²PAK Package Mechanical Data



		DIMEN	ISIONS	
REF.	Millim	neters	Inches	
	Min.	Max.	Min.	Max.
Α	4.40	4.60	0.173	0.181
A1	2.49	2.69	0.098	0.106
A2	0.03	0.23	0.001	0.009
В	0.70	0.93	0.027	0.037
B2	1.14	1.70	0.045	0.067
С	0.45	0.60	0.017	0.024
C2	1.23	1.36	0.048	0.054
D	8.95	9.35	0.352	0.368
Е	10.00	10.40	0.393	0.409
G	4.88	5.28	0.192	0.208
L	15.00	15.85	0.590	0.624
L2	1.27	1.40	0.050	0.055
L3	1.40	1.75	0.055	0.069
М	2.40	3.20	0.094	0.126
R	0.40 typ.		0.016	6 typ.

Figure 21: Foot Print Dimensions

(in millimeters)

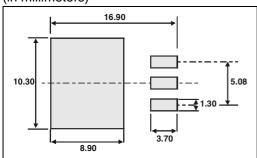


Table 7: Ordering Information

Part Number	Marking	Package	Weight	Base qty	Delivery mode
ACST8-8CFP	ACST88C	TO-220FPAB	2.4 g	50	Tube
ACST8-8CT		TO-220AB	2.3 g	50	Tube
ACST8-8CG		D ² PAK	1.5 g	50	Tube
ACST8-8CG-TR		DIAK	1.5 g	500	Tape & reel

■ Epoxy meets UL94, V0

Table 8: Revision History

Date	Revision	Description of Changes
Jan-2002	4B	Last update.
08-Nov-2004	5	TO-220AB and D ² PAK packages added.
24-Nov-2004	6	Table 6 page 3: I _{GT} parameter added



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